## NSN 5962-01-381-7744

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Electrostatic sensitive and programmed and ultraviolet erasable and high impedance and w/enable and w/clock and asynchronous and
w/reset and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Control of the Control
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Current Rating Per Characteristic:
180.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
8.00 input picofarads and 8.00 output picofarads
Time Rating Per Chacteristic:
35.00 nanoseconds access
Memory Device Type:
Pal
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
40 printed circuit
Shelf Life:
N/a
Unit Of Measure:
<del></del>
Demilitarization:
No
Fiig:
A458a0